



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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**CMOSH2-4L**

**SURFACE MOUNT SILICON  
HIGH CURRENT  
LOW  $V_F$  SCHOTTKY DIODE**

**SOD-523 CASE**[www.centrasemi.com](http://www.centrasemi.com)**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMOSH2-4L is a high current, low  $V_F$  silicon Schottky diode in an SOD-523 surface mount package. This device offers a  $V_F$  as low as 0.33 volts and is designed for small signal general purpose applications where size and low loss is required.

**MARKING CODE: 4L****MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$ )

Peak Repetitive Reverse Voltage  
Continuous Forward Current  
Peak Repetitive Forward Current  
Peak Forward Surge Current,  $t_p=10\text{ms}$   
Power Dissipation  
Operating and Storage Junction Temperature  
Thermal Resistance

**SYMBOL**

$V_{RRM}$  40  
 $I_F$  200  
 $I_{FRM}$  350  
 $I_{FSM}$  1.0  
 $P_D$  250  
 $T_J, T_{stg}$  -65 to +150  
 $\Theta_{JA}$  500

**UNITS**

V  
mA  
mA  
A  
mW  
 $^\circ\text{C}$   
 $^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

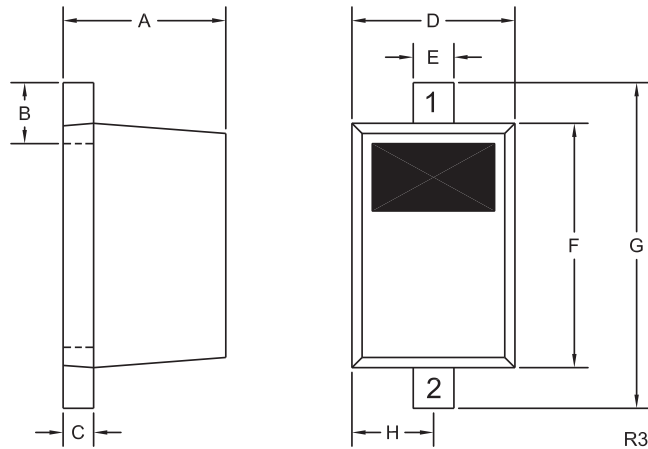
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
$I_R$	$V_R=20\text{V}$		11	50	$\mu\text{A}$
$BV_R$	$I_R=100\mu\text{A}$	40	53		V
$V_F$	$I_F=10\text{mA}$		0.24	0.325	V
$V_F$	$I_F=100\text{mA}$		0.35	0.4	V
$V_F$	$I_F=200\text{mA}$		0.42	0.5	V
$C_J$	$V_R=4.0\text{V}$ , $f=1.0\text{MHz}$		8.5	10	pF
$t_{rr}$	$I_F=I_R=10\text{mA}$ , $I_{rr}=1.0\text{mA}$ , $R_L=100\Omega$		4.0	5.0	ns

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SOD-523 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Cathode
- 2) Anode

MARKING CODE: 4L

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.020	0.031	0.50	0.80
B	0.008	0.016	0.20	0.40
C	0.002	0.008	0.05	0.20
D	0.028	0.035	0.70	0.90
E	0.008	0.014	0.20	0.35
F	0.039	0.055	1.00	1.40
G	0.055	0.071	1.40	1.80
H	0.016		0.40	

SOD-523 (REV: R3)

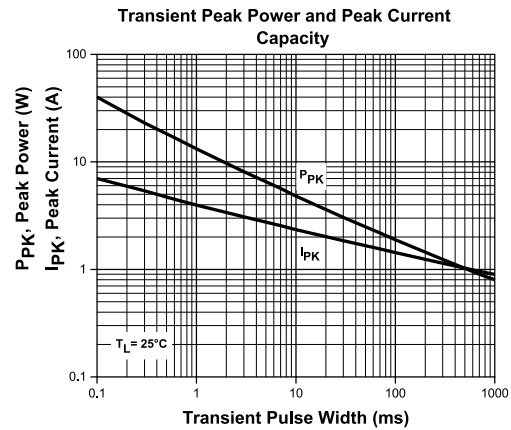
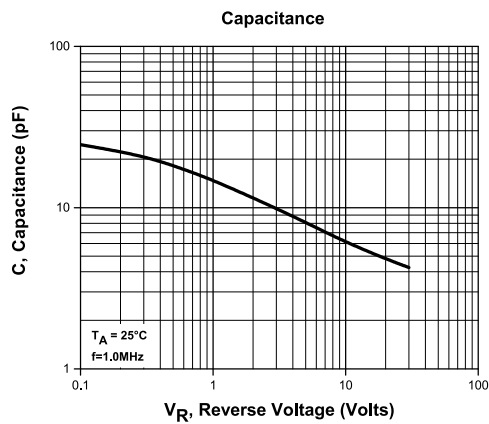
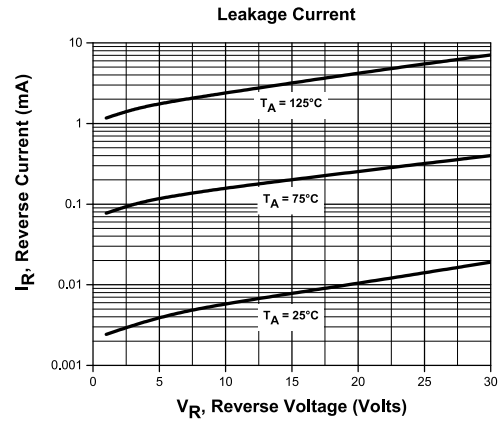
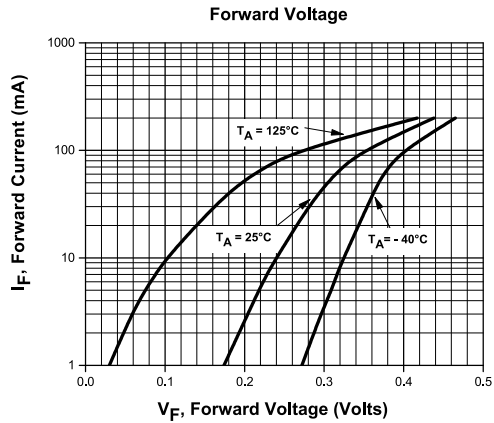
R6 (13-November 2015)

CMOSH2-4L

SURFACE MOUNT SILICON  
HIGH CURRENT  
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## TYPICAL ELECTRICAL CHARACTERISTICS



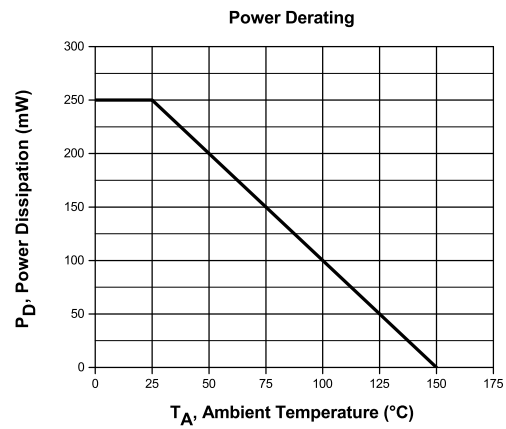
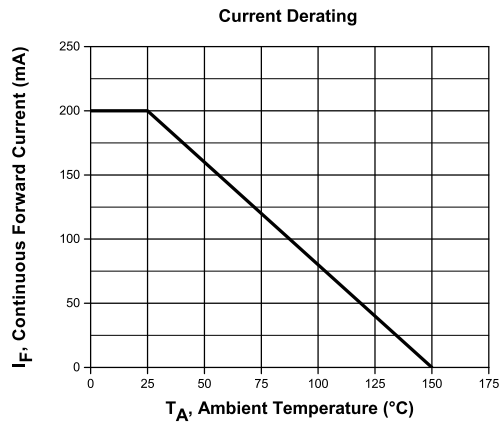
R6 (13-November 2015)

CMOSH2-4L

SURFACE MOUNT SILICON  
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### TYPICAL ELECTRICAL CHARACTERISTICS



R6 (13-November 2015)



## OUTSTANDING SUPPORT AND SUPERIOR SERVICES



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### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

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### DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

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### REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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### CONTACT US

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